

SILVACO

GUIDE TO USING TCAD WITH EXAMPLES

(PC VERSION)

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September 16, 2009

Table of Contents

Chapter 1: Introduction	3
Chapter 2: Getting Started With Just a Few Clicks of the Mouse.....	4
Section 2.1: The DeckBuild Runtime Environment Window	4
Section 2.2: Loading and Running Examples	5
Section 2.3: Viewing the Results	9
Chapter 3: Navigating the Manual and Self Training the Easy Way	12
Chapter 4: Other Web Based Information	15

Chapter 1:

Introduction

This manual is intended for the first time user of SILVACO TCAD products. Its intention is to enable a new user to have the software up and running within a few minutes of successful installation.

This tutorial will also demonstrate how to navigate the manuals quickly and efficiently to locate explanations and definitions of all parameters used in the simulators. It will cross reference the user to the relevant physics chapters to understand the equations and underlying physics in which these equations are used.

For further reading and references, the reader will be directed to a wealth of technical material and published paper references located in the technical sections of the SILVACO web pages.

Chapter 2:

Getting Started With Just a Few Clicks of the Mouse

Section 2.1: The DeckBuild Runtime Environment Window

The key to rapid familiarization with SILVACO's TCAD software is the versatile and feature laden runtime environment called "DeckBuild." DeckBuild features include: editing of new or existing input files, creation of Design Of Experiments (DOE), powerful parameter extraction routines and the ability to make anything in the input file a variable.

Most importantly for the first time user however, DeckBuild includes literally hundreds of examples for many different types of electrical, optical and magnetic technologies.

Getting Started...

Double click on the DeckBuild icon. (see Figure 2.1.)

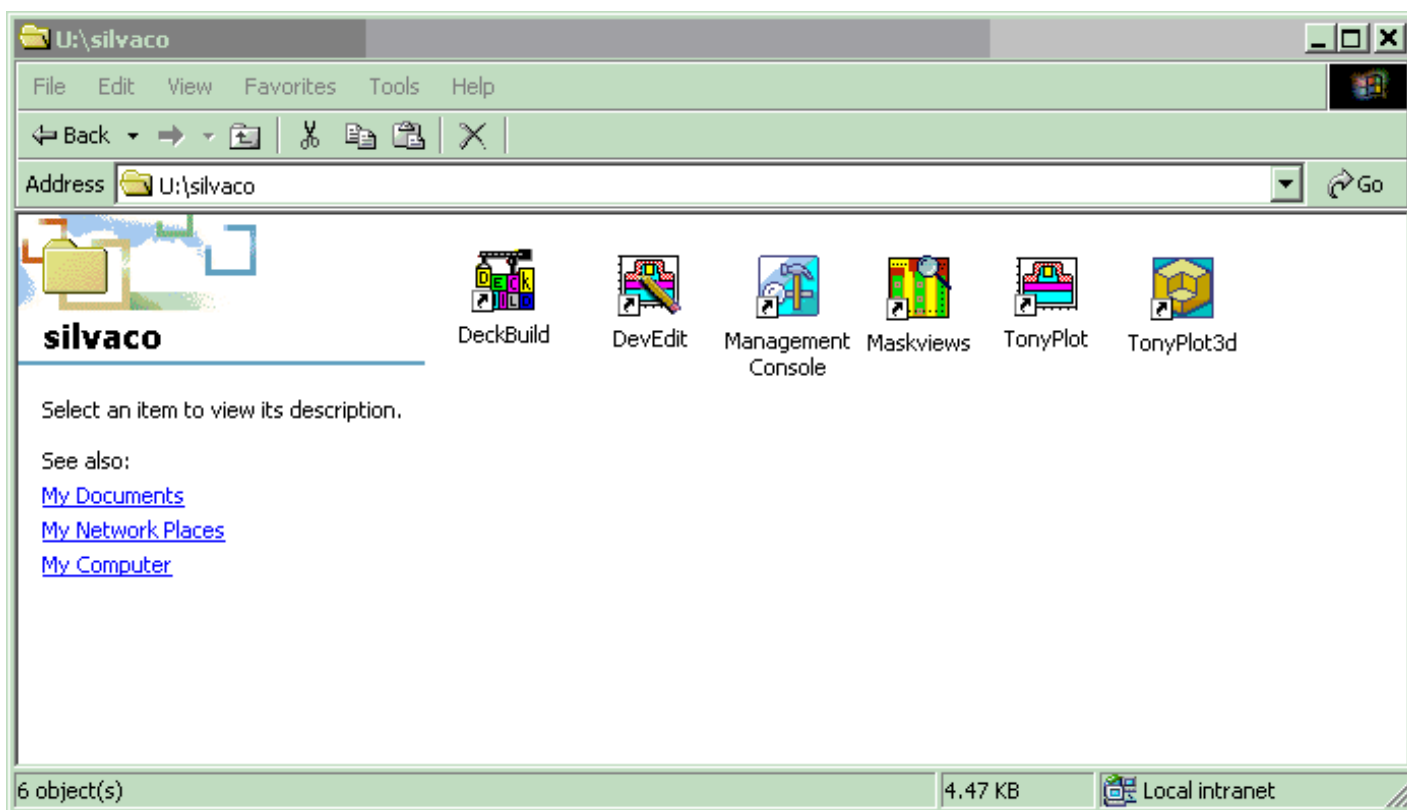


Figure 2.1.

You should see the DeckBuild runtime environment appear on your monitor and it should look very similar to that shown in Figure 2.2.

The GUI interface is arranged in two parts. The upper window displays the current input file and the lower window displays the output created when running that input file.

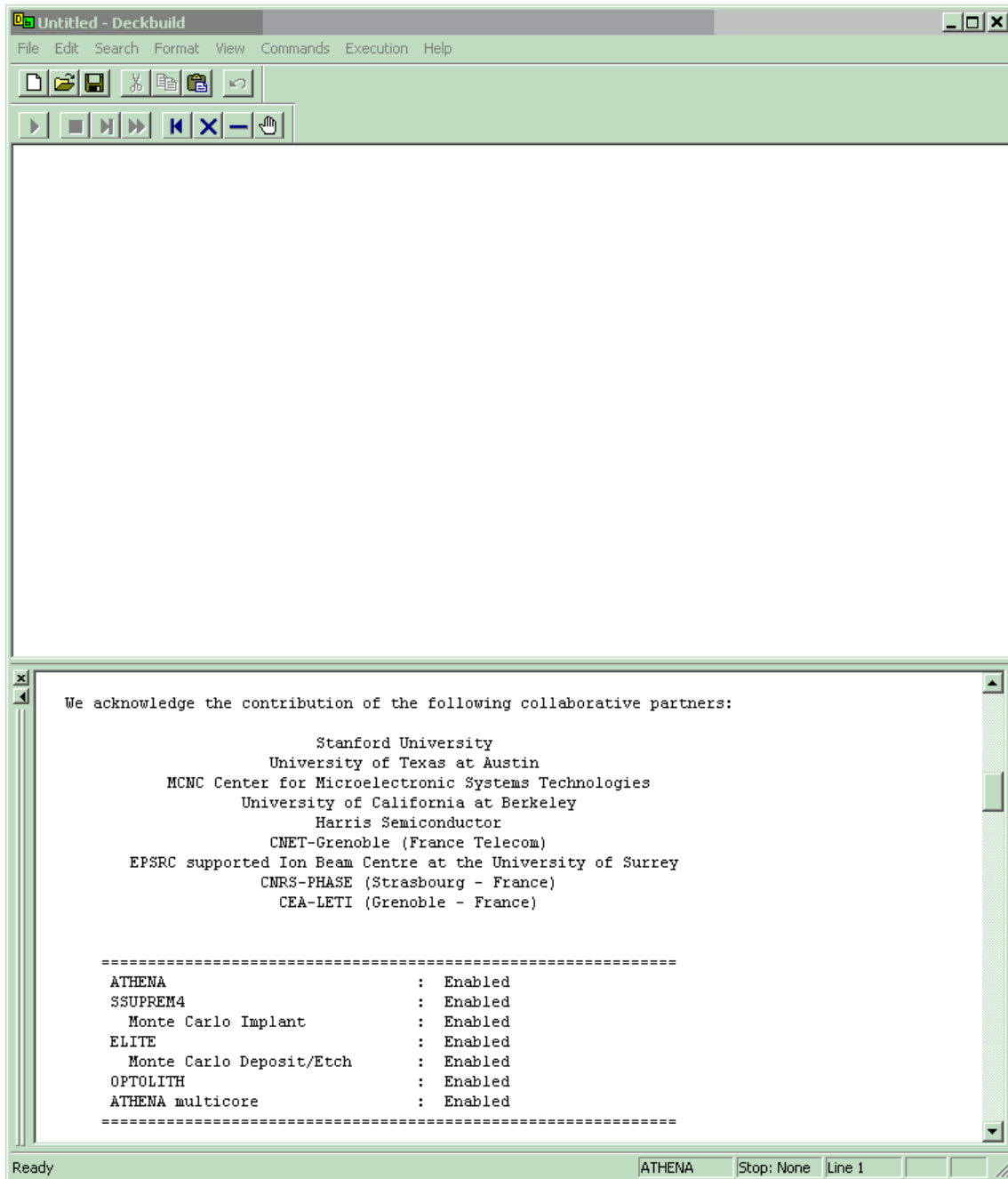


Figure 2.2. The DeckBuild Runtime Interface GUI.

Section 2.2: Loading and Running Examples

The input file can be created by the user or can be loaded from the examples library. Familiarization with the software syntax is best executed by loading an example in the first instance. To load an example from the DeckBuild runtime environment GUI, click:

Help... Examples...

A pop up window displays a list of 47 different categories of examples. The first 7 categories are displayed as shown in Figure 2.3. To view the remaining categories, simply scroll down using the slider on the right hand side of the window.

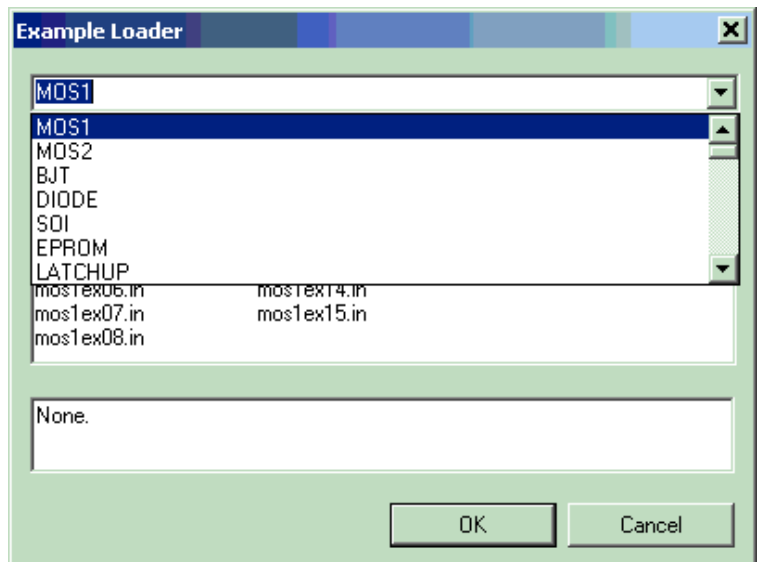


Figure 2.3. The First 7 DeckBuild Example Categories.

To view a listing of the examples in each category, double-click one of the categories. If you double-click the first category entitled “MOS1,” you will get the listing shown in Figure 2.4. There are 15 examples in this category.

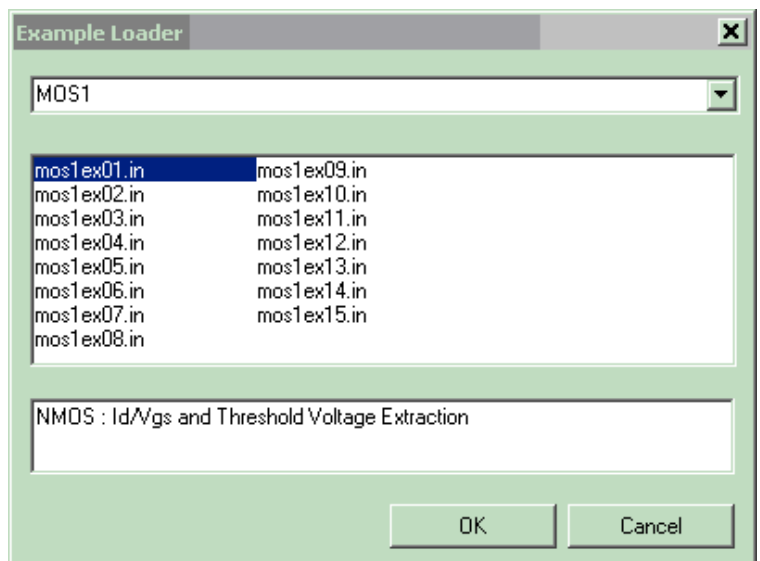


Figure 2.4. MOS1 Application Example List.

In order to load this particular example into the DeckBuild runtime environment select the required example with the left mouse button, then click “OK”. The main DeckBuild window should now appear as in Figure 2.5.

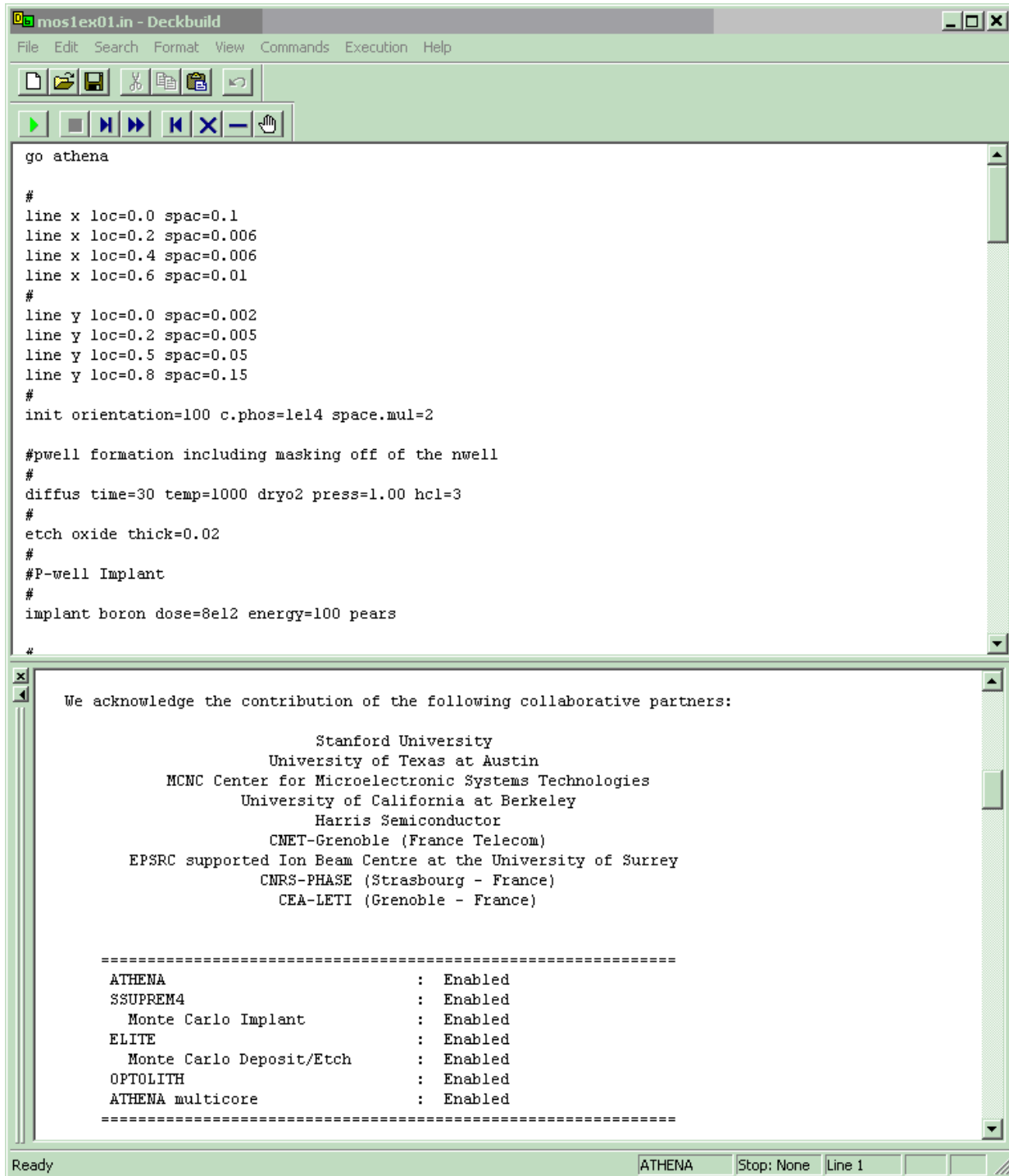


Figure 2.5. Example Input File Now Loaded Into DeckBuild.

Running the example is simply a matter of clicking the “run” button (green forward arrow icon). On completion, two plots will appear on the screen. The first is a color contour plot of the process simulated structure displaying “Net Doping” and the second is a simple threshold voltage, V_g versus I_d plot. These plots are shown in Figures 2.6 and 2.7 respectively. It should be noted that it is not necessary to actually run the simulations in order to view the results, since these structure files and line graphs are loaded into the current working directory as soon as the “OK” button is selected.

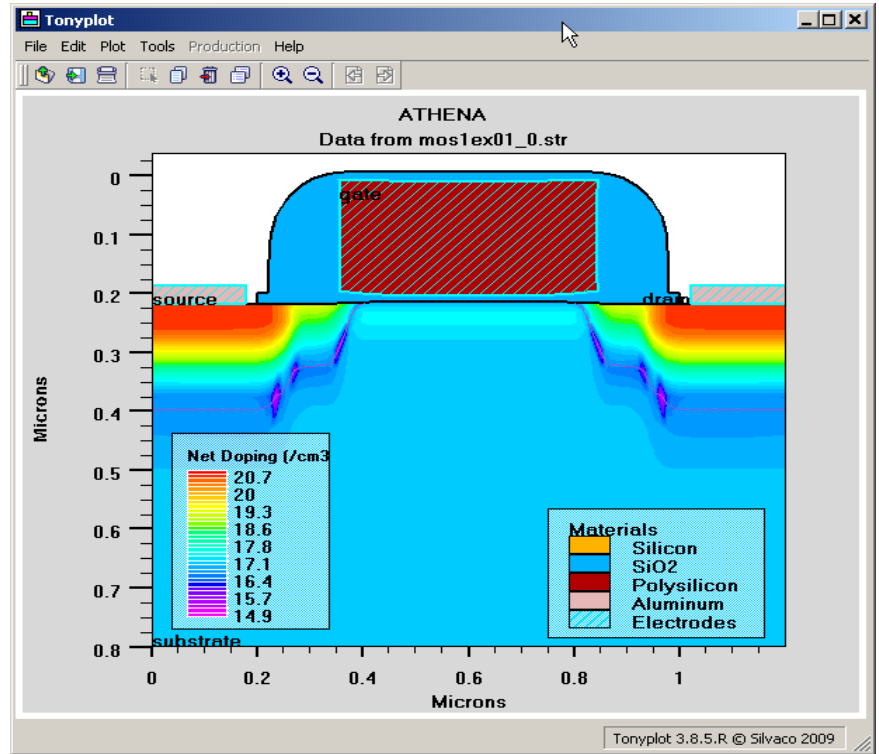


Figure 2.6. Process Simulated Structure Showing Net Doping.

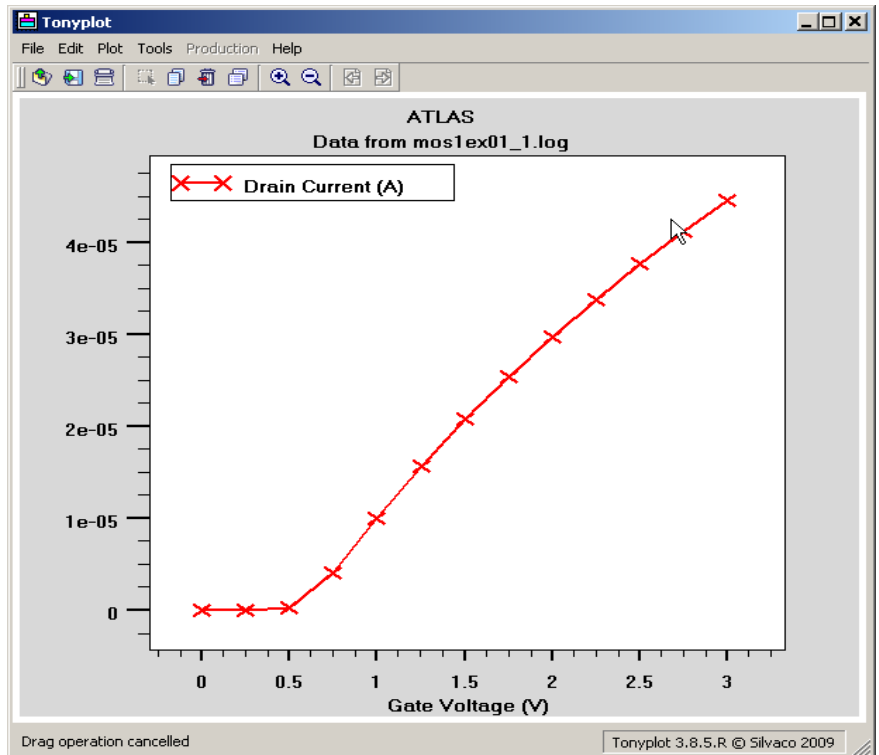


Figure 2.7. Device Simulated Line Graph Showing V_g Versus I_d .

Section 2.3: Viewing the Results

SILVACO's visualization tool called "TonyPlot" is a feature-packed plotting program. We will only touch on some of its more basic capabilities in this tutorial. When a structure file or line graph is saved in SILVACO's TCAD package, almost every quantity required to create the structure file or line graph, will be automatically included into the file and will be available for plotting.

For example, in the structure file plot, if you wish to plot other calculated quantities such as "Donor Concentration," click the following sequence:

Plot... Display... Define... Contours...

then pull down and scroll the "Quantity:" box to obtain a list of plottable quantities. If you followed the sequence, two additional GUI displays should appear as in Figure 2.8. Select any new quantity and click "Apply."

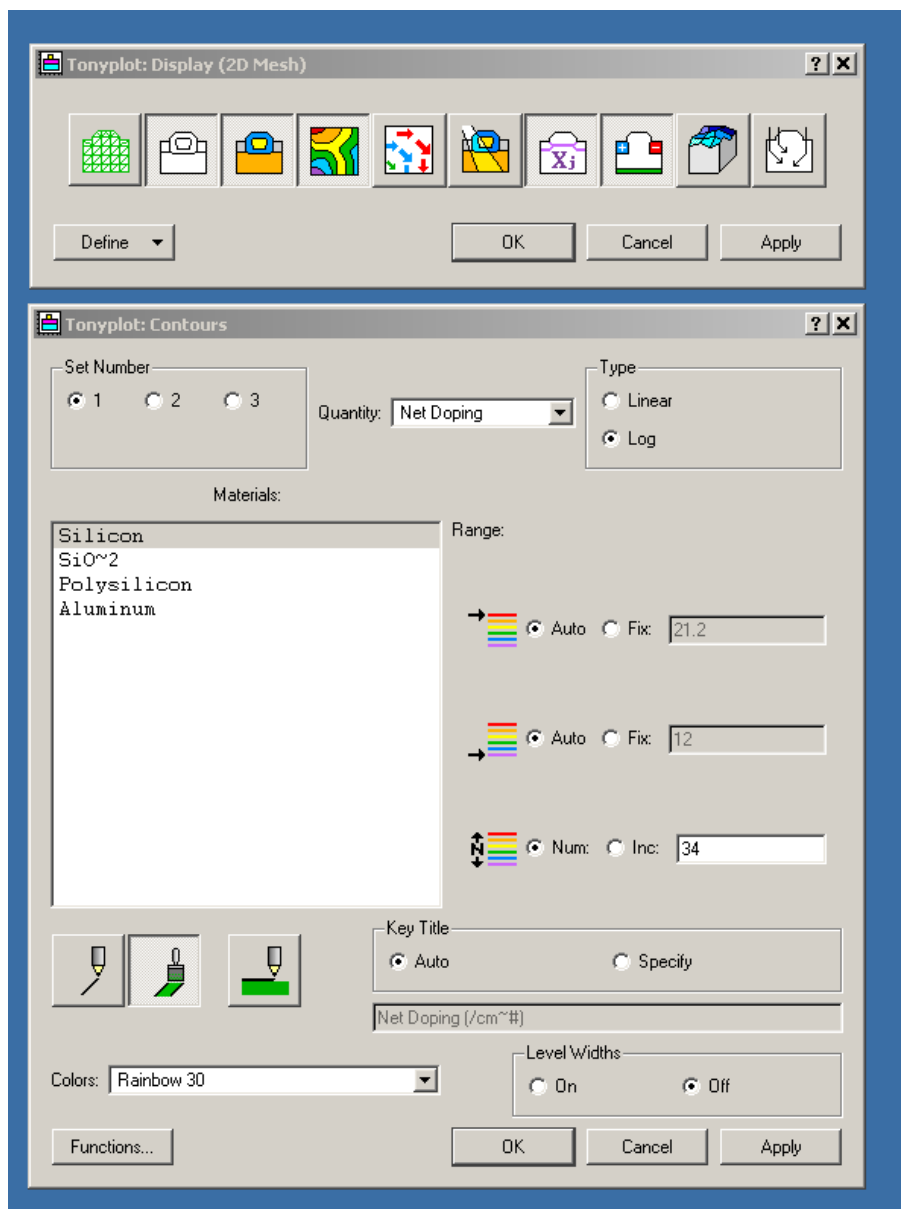


Figure 2.8. The GUIs Related to Selecting Plottable Quantities.

It will often be necessary to view a “cutline” slice through a plot. To do this, close other plotter related windows by clicking “OK,” then return to the main plot and select the following sequence:

Tools... Cutline...

For now we will use the default “vertical cutline” box, but the horizontal or diagonal cutline box could also be selected in the “cutline” GUI. Return to the main plot, click and hold down the left mouse button where you want to start the cutline. Drag the mouse vertically and let go of the left mouse button where you wish to finish the cutline. When you let go of the left mouse button, the cutline plot will automatically appear showing a cutline of the currently displayed quantity. Click “OK” on the cutline box if you are now done with making cutlines.

To overlay other quantities on the new cutline graph, left click the line graph to make it the current active plot (a white border around the plot indicates which plot is currently active). Now click:

Plot... Display...

and select other quantities to overlay on the line graph. For example, if you add Arsenic, Boron and Phosphorus to the line graph, it should now appear as in Figure 2.9. A similar sequence on the V_g versus I_d curve will also allow other electrical quantities to be overlaid on that line graph.

To plot a structure file created during a simulation automatically, simply add the lines:

```
structure outfile=<filename>  
tonyplot <filename>
```

into your input file and the simulator will save the structure file created up until that point in the input file. It will then plot it automatically once the simulator reaches that point. You can save and plot as many structure files as you wish at any point during the simulation.

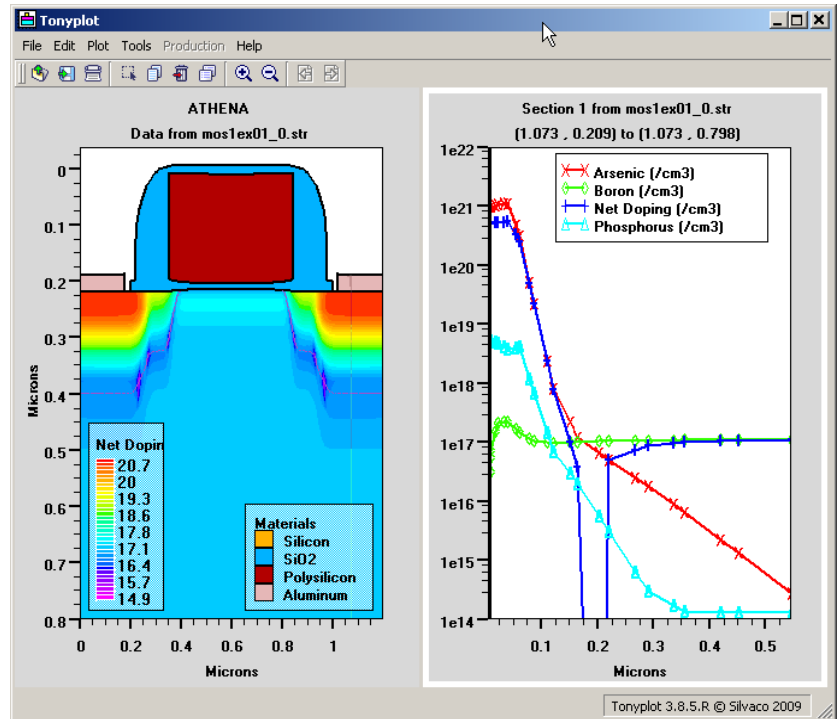


Figure 2.9. Cutline Graphs.

Chapter 3:

Navigating the Manual and Self Training the Easy Way

At first sight, the size of the manuals may seem a little daunting, but this section will show the new user just how simple it is to find the specific information required by using the examples to navigate the manual.

Using the input file we loaded in Section 2.2 as an example, let us say we wanted to understand what the “SRH” parameter does in the device simulation section of the input file, which appears on the line beginning with “models.”

In both the process and device simulator, the first word on any line is known as the “statement.” In this example, since the first word on the line is “models” we now know that we need more information on the “models statement” if we are to find out what the parameter “SRH” means.

All SILVACO products include manuals in pdf format. We are looking for information in the device simulator, so we need to invoke the ATLAS manual. The manuals can be accessed via the “sman” facility which can be invoked by clicking the “Management Console” icon. Figure 3.1 shows what the manual should look like.

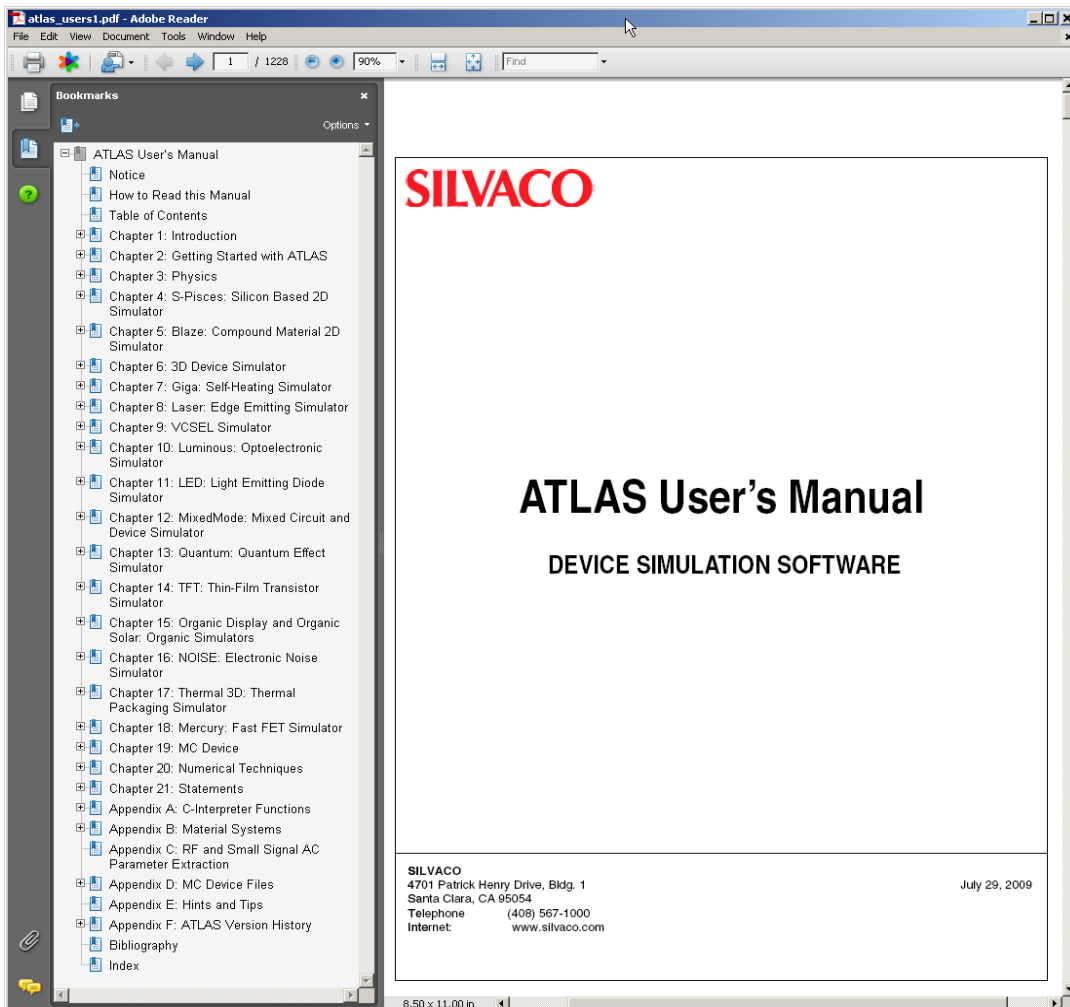


Figure 3.1 The ATLAS Manual PDF Interface.

One of the most powerful features of the manual is the “Statements” chapter. This chapter contains an alphabetical listing of all the statements in the device simulator. Since we are looking for information on the “models” statement, click on the expansion “+” symbol next to the Statements chapter in the Index located on the left side of the page. Scroll down the alphabetical listings until you reach the “Models” statement. Click the expansion “+” sign next to the Models statement to see its contents.

At this point, we now have a choice. If you have already guessed that “SRH” is an acronym for “Schottky Read Hall” recombination, then click the section titled “Recombination Models Flags.” If you had no idea what the parameter “SRH” was, click the “MODELS” heading to start at the beginning of this section. At the beginning of this section is another alphabetical listing of all parameters associated with the models statement. Scroll down until you reach “SRH” and the table will inform you: what type of parameter it is, any default value applied to it and what the units of the parameter are. Once you know what kind of parameter it is, scroll down the rest of the section until you find it in the description section below. You could also use the “Edit... Find...” feature to search for “SRH” in the description section. Whichever method used, you should now be located at the section where a brief description of the SRH parameter is given, as shown in Figure 3.2.

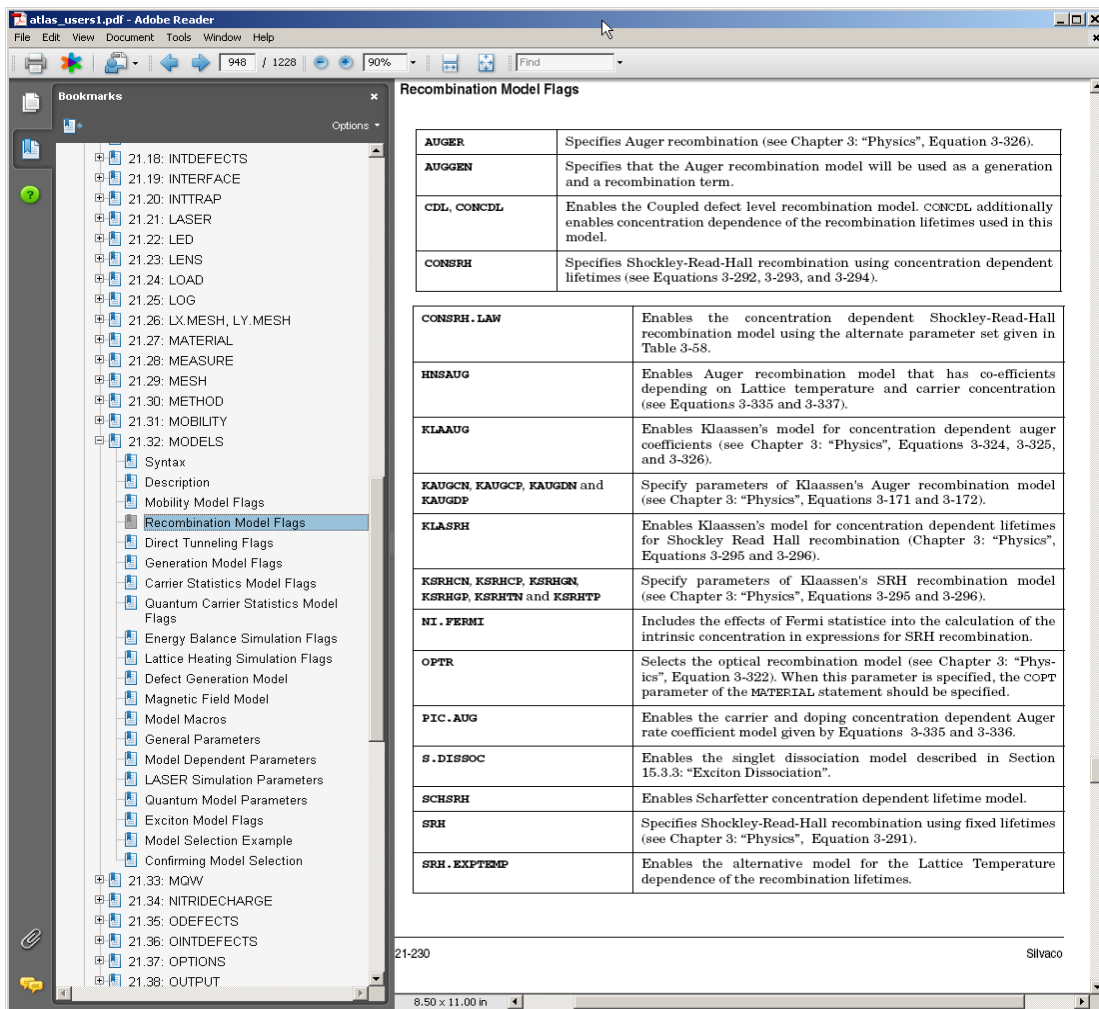


Figure 3.2 Locating the Description of the “SRH” Parameter.

This information may be sufficient for the user to know what the parameter is and its default values. If however, you now wish to understand the physics and formulas in which this parameter is used, the description for ‘SRH’ in the Statements Chapter, cross references the reader to the Physics Chapter 3, Equation 3-290 to find out more information. If you cross references to Equation 3-290, we find a full description of the SRH model, as shown in Figure 3.3.

Physics

Shockley-Read-Hall (SRH) Recombination

Phonon transitions occur in the presence of a trap (or defect) within the forbidden gap of the semiconductor. This is essentially a two step process, the theory of which was first derived by Shockley and Read [188] and then by Hall [77]. The Shockley-Read-Hall recombination is modeled as follows:

$$R_{SRH} = \frac{pn - n_{ie}^2}{TAUP0 \left[n + n_{ie} \exp\left(\frac{ETRAP}{kT_L}\right) \right] + TAUN0 \left[p + n_{ie} \exp\left(\frac{-ETRAP}{kT_L}\right) \right]} \quad 3-290$$

where ETRAP is the difference between the trap energy level and the intrinsic Fermi level, T_L is the lattice temperature in degrees Kelvin and TAUN0 and TAUP0 are the electron and hole lifetimes. This model is activated by using the SRH parameter of the MODELS statement. The electron and hole lifetime parameters, TAUN0 and TAUP0, are user-definable in the MATERIAL statement. The default values for carrier lifetimes are shown in Table 3-56. Materials other than silicon will have different defaults. A full description of these parameters are given in Appendix B: “Material Systems”.

Statement	Parameter	Default	Units
MATERIAL	ETRAP	0	eV
MATERIAL	TAUN0	1×10^{-7}	s
MATERIAL	TAUP0	1×10^{-7}	s

Note: This model only presumes one trap level which, by default, is ETRAP=0 and it corresponds to the most efficient recombination centre. If the TRAP statement is used to define specific trap physics then separate SRH statistics are implemented as described earlier in “Trap Implementation into Recombination Models” section on page 3-16.

Figure 3.3 The Full Description of the SRH Model Cross Referenced.

With a few clicks of the mouse, we have found what a parameter is, together with a full physical description of how this parameter works in the simulator and what other user definable parameters are in the equation that are under the users control. Now you understand how the manuals work in conjunction with the examples.

Chapter 4: Other Web Based Information

The SILVACO website offers a wealth of technical information in our library section currently located at:

http://www.silvaco.com/tech_lib/index.html

Here information is sorted into four categories, namely:

- 1/ Simulation Standard (a SILVACO publication)
- 2/ Presentation Materials
- 3/ Books published referencing SILVACO Software
- 4/ Published Papers (Peer Reviewed Technical Publications)

SILVACO's Simulation Standard is a quarterly TCAD publication that includes detailed application notes and results of simulations covering a wide range of technologies. There is also a Hints and Tips section that answers some frequently asked questions. All Simulation Standard publications, dating back for many years, are available on the SILVACO web site. Use the search facility to find an article on the subject you are interested in.

The documents under the heading "Presentation Materials" contain several types of presentations. There are PowerPoint presentations showing application examples and explanations of syntax etc. There are also academic course materials showing how to incorporate SILVACO TCAD software into coursework. Other sections list patents aided by SILVACO software plus a listing of text books referencing SILVACO software.

The final two sections in the Technical Library section list text books and published papers under numerous technology headings that have all used SILVACO software in their creation.

If this all seems like information over-load, SILVACO has once again made searching for information as simple as possible by including a search box that quickly and efficiently takes the user to the information required.

In conclusion we hope we have demonstrated just how simple it is to use SILVACO software and to find the information you need to teach yourself how to succeed in your TCAD simulations.